

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

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Title of Invention	METHOD OF FORMING A SEMICONDUCTOR DEVICE HAVING AIR GAPS AND THE STRUCTURE SO FORMED
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Application Number :

Confirmation Number:

First Named Applicant: Anthony Stamper

Attorney Docket Number: BUR920030189US1

Art Unit:

Examiner:

Search string: (6603204 or 6596624 or 6596467 or 6589644 or 6577011 or 6479374 or 6413852 or 6387824 or 6362091 or 6319854 or 6287979 or 6265780 or 5994776 or 5965202 or 5548159 or 5470801 or 5468685 or 5461003 or 20030114013).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6603204	2003-08-05	Gates et al			
	2	6596624	2003-07-22	Romankiw			
	3	6596467	2003-07-22	Gallagher et al			
	4	6589644	2003-07-08	Yamada et al			
	5	6577011	2003-06-10	Buchwalter et al			
	6	6479374	2002-11-12	Ioka et al			
	7	6413852	2002-07-02	Grill et al			
	8	6387824	2002-05-14	Aoi			
	9	6362091	2002-03-26	Andideh et al			
	10	6319854	2001-11-20	Aoi			
	11	6287979	2001-09-11	Zhou et al			
	12	6265780	2001-07-24	Yew et al			
	13	5994776	1999-11-30	Fang et al			
	14	5965202	1999-10-12	Taylor-Smith et al			
	15	5548159	1996-08-20	Jeng			
	16	5470801	1995-11-28	Kapoor et al			
	17	5468685	1995-11-21	Orisaka et al			
	18	5461003	1995-10-24	Havemann et al			

US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
	1	20030114013	2003-06-19	Hedrick et al			

Signature

Examiner Name	Date